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Loop transducer matching for low insertion loss magnetostatic surface wave resonator

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In this paper we describe the matching of a loop transducer to significantly reduce the insertion loss and to improve the off-resonance rejection of a magnetostatic surface wave resonator.

INTRODUCTION

Magnetostatic wave (MSW) devices1–8 form the basis of a new class of emerging microwave analog signal processing devices. Among these devices, MSW resonators and the corresponding loop transducers can be fabricated using conventional UV photolithography. It provides broad frequency tunability (2–18 GHz) by an external magnetic field. The insertion loss is low, and the Q is moderate, whereas for acoustic wave resonators one needs submicron photolithography. Although Q is usually high the insertion loss is also very high at microwave frequencies. It is well known that yttrium iron garnet sphere resonators operate well at microwave frequencies but require tedious and expensive fabrication procedures. MSW techniques, however, provide a simpler means of obtaining very high Q resonators for MSW oscillator and complex filter functions. In an earlier paper9 I discussed the magnetostatic surface wave (MSSW) resonators in detail. In this paper I focus on how the matching of the loop transducer with MSSW resonators was done.

We initially prepared 3-mm-wide, 1-in-long MSSW resonators on epitaxially grown YIG films on GGG substrates by usual standard UV photolithography techniques. To drive these resonators in the 2–6 GHz region we fabricated microstrip loop transducers (see Fig. 1) (MSW wavelength was chosen to be 300 μm). The MSSW resonators are driven with structure A of Fig. 1 in flipped configuration on structure B. Although the resulting Q (quality factor) of the resonators driven by the said loop transducers were in the region 800–3000 in the frequency range 3–6 GHz, the corresponding insertion losses were very high (15–34 dB) when 3-mm-long microstrip loop transducers were used. Moreover, the 3-mm-wide resonators with 3-mm-long loop transducer combinations were not tunable beyond 4.5 GHz because of the occurrence of the uniform resonance mode with IL higher than the MSSW mode and very low Q. Using a 1-mm-wide resonator with a 1-mm-long microstrip loop transducer (λMSW = 300 μm, separation between the loop microstrips is 150 μm, see Fig. 2) the insertion loss was reduced to 8–20 dB. The different resonator responses with both matched and unmatched transducers are shown in Tables I and II. In order to reduce the insertion loss further, it was necessary that a 1-mm-long microstrip loop transducer was matched to 50-Ω input–output load, at resonance. The matching significantly improved the tunability over a very wide frequency range and the insertion losses and the off-resonance rejection of the resonators. (See Table II and Figs. 3 and 4.)

For matching, S11 parameters (both magnitude and phase) were determined using a HP network analyzer with the resonator I (see Tables I and II) at several frequencies over 3–6 GHz. Before measuring the S11 parameters, the S11 channel of the network analyzer was adjusted so that the S11 magnitude and phase were 1° and 180°, respectively, at each frequency in the range 3–6 GHz when a 1-mm transducer short was used alone. The transducer short was made by grounding at the input of the microstrip of an identical loop transducer. The resonator was then set at resonance at the same frequency and the S11 parameters were determined (thus the S11 parameters were determined with respect to the transducer short). S11 parameters were plotted on a Smith chart (see Fig. 5) and the primary matching design as followed as provided by Hewlett-Packard Application Note 154. As matching over an octave band of 3–6 GHz is difficult, we tried finally to optimize the matching through computer optimization of microwave passive and active circuits (COMPACT). The circuit which optimized the matching is shown in Fig. 2(a) (assuming it is built on 250-μm quartz substrates which have εr = 3.8). The widths W1 and W2 of the transmission line microstrips AB and CD as obtained from COMPACT were 0.52 and 0.55 mm, respectively, and the corresponding lengths were 6 and 5 mm, respectively [see Figs. 2(a) and 2(b)]. The values of L = 1.51 nH and C = 0.3 pF [Fig. 2(a)] were also obtained from COMPACT. The optimized S11 parameters within 400–5850 MHz are also shown in Fig. 5. We were not concerned about optimization in the range 3–4 GHz, because the insertion loss at resonance was within 6–12 dB even with an unmatched 1-mm transducer.

FIG. 1. A general schematic of a MSSW resonator with the corresponding loop transducer. The dimension of a typical resonator is 25 mm × 1 mm × 264 μm (14-μm YIG film on 250-μm GGG substrate).

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MICROSTRIP MATCHED CIRCUIT

In order to fabricate the above-mentioned computer optimized circuit of Fig. 2(a) on 250-μm-thick quartz substrates in the form of microstrips only, it was necessary to utilize the inductance and capacitance of the microstrips so that the required inductance of \( L = 1.51 \text{nH} \) and the capacitance \( C = 0.3 \text{ pF} \) could be introduced in the microstrips without the necessity of lumped components. The microstrip structure of Fig. 2(b) was found to be very convenient for photolithographic reproduction on quartz substrates. Its equivalent circuit is shown in Fig. 2(c). To calculate the required lengths \( l_f \) and the width \( W \) of the microstrip between B and C, the following points were taken into account:

1. High impedance microstrip line \((Z_{0L} = 100 \Omega)\) was used for inductance. The required length \( l_f \) and the width \( W \) of the microstrip line of the inductance 1.5 nH and capacitance of 0.3 pF [see Fig. 2(b)] were determined below.

2. Discontinuity capacitance and inductance (at points A, B, and C) were utilized to provide the required \( L \) and \( C \) in the circuit as shown in Figs. 2(b) and 2(c).

### TABLE I. Physical characteristics of the resonators.

<table>
<thead>
<tr>
<th>Resonator No.</th>
<th>Number of arrays (μm)</th>
<th>( L ) (μm)</th>
<th>( C ) (μm)</th>
<th>Depth of grooves (mm)</th>
<th>YIG thickness (μm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>X1</td>
<td>40</td>
<td>65</td>
<td>80</td>
<td>3</td>
<td>1.1</td>
</tr>
<tr>
<td>X2</td>
<td>60</td>
<td>75</td>
<td>72</td>
<td>1.5</td>
<td>0.32</td>
</tr>
<tr>
<td>X6</td>
<td>55</td>
<td>70</td>
<td>72</td>
<td>3</td>
<td>0.4</td>
</tr>
<tr>
<td>K8</td>
<td>70</td>
<td>70</td>
<td>76</td>
<td>3.6</td>
<td>0.34</td>
</tr>
<tr>
<td>K2</td>
<td>60</td>
<td>75</td>
<td>76</td>
<td>3.0</td>
<td>0.42</td>
</tr>
<tr>
<td>K2'</td>
<td>65</td>
<td>70</td>
<td>76</td>
<td>3.0</td>
<td>0.62</td>
</tr>
<tr>
<td>I</td>
<td>70</td>
<td>72</td>
<td>72</td>
<td>3.6</td>
<td>0.7</td>
</tr>
<tr>
<td>X11</td>
<td>60</td>
<td>63</td>
<td>81</td>
<td>1.5</td>
<td>0.33</td>
</tr>
</tbody>
</table>

### TABLE II. Summary of resonators' response data.

<table>
<thead>
<tr>
<th>Resonator No.</th>
<th>Aperture (mm)</th>
<th>Frequency (GHz)</th>
<th>Insertion loss (dB)</th>
<th>Optimized ( Q ) ± 10</th>
<th>Resonance clearance (dB)</th>
</tr>
</thead>
<tbody>
<tr>
<td>X1</td>
<td>1</td>
<td>3</td>
<td>8</td>
<td>300 8</td>
<td></td>
</tr>
<tr>
<td>X3</td>
<td>1</td>
<td>3</td>
<td>17</td>
<td>650 7</td>
<td></td>
</tr>
<tr>
<td>X6</td>
<td>3</td>
<td>10</td>
<td>400</td>
<td></td>
<td>9</td>
</tr>
<tr>
<td>X11</td>
<td>3</td>
<td>13</td>
<td>400</td>
<td></td>
<td>7</td>
</tr>
<tr>
<td>K8</td>
<td>1</td>
<td>11</td>
<td>500</td>
<td></td>
<td></td>
</tr>
<tr>
<td>K2</td>
<td>1.5</td>
<td>12</td>
<td>550</td>
<td></td>
<td>8</td>
</tr>
<tr>
<td>K2</td>
<td>1</td>
<td>3</td>
<td>850</td>
<td></td>
<td>9</td>
</tr>
<tr>
<td>I</td>
<td>1</td>
<td>3</td>
<td>1500</td>
<td></td>
<td>15</td>
</tr>
</tbody>
</table>

\( L \) is the equivalent circuit of the microstrip discontinuities.

The frequency \( f = 4.5 \text{ GHz} \) in the following equations\(^{10}\) was chosen to be the center of the 3-6 GHz band:

\[
\varepsilon_{\text{eff}}(f) = \varepsilon_r - \frac{\varepsilon_r - \varepsilon_{\text{eff}}}{(1 + (h/Z_0)^{1.5})(0.43f^2 - 0.009f^3)},
\]

for \( Z_{\text{oc}} < 50 \Omega \),

\[
\varepsilon_{\text{eff}} = \varepsilon_r / 0.96 \varepsilon_s + (0.109 - 0.004 \varepsilon_s) \{\log(10 + Z_{\text{oc}}) - 1\}
\]

Figure 3. (a) Resonator response at 6 GHz. 1-mm resonator K2 is used with a 1-mm matched transducer. It is seen that the \( S_{21} \) notch (lower curve) coincides with the \( S_{21} \) peak (upper) trace. Sweep range = 1 GHz.

(b) The same resonator as K2 at 6 GHz with unmatched 1-mm loop transducer. We see that the \( S_{21} \) notch does not coincide with the \( S_{21} \) peak and the insertion loss is higher. Moreover the off-resonance rejection is also lower than in (a).
FIG. 4. (a) Shows the resonator response with the resonator X1 and 1-
mm matched transducer at 3.75 GHz. Insertion loss close to 7 dB had
been achieved. The $S_{11}$ peak coincides with $S_{11}$ peak as is expected
for good matching. Before matching the latter was occurring at 83 MHz
higher [part (b)]. Matching improved the insertion loss in this case
by 8 dB. (b) Shows the same resonator response with an unmatched trans­
ducer. As before we see that the $S_{11}$ notch does not coincide with the $S_{11}$
peak B.

![Graph showing resonator response](image)

$\frac{\varepsilon \rho}{2} = \frac{\varepsilon + 1}{2} \left[ 1 + \frac{29.98}{Z_{e00}} \left( \frac{2}{\varepsilon + 1} \right)^{0.5} \right] \times \frac{\varepsilon - 1}{\varepsilon + 1} \left( \frac{\ln \pi / 2 + \ln 4}{\varepsilon} \right)^{0.5}, \quad (3)$

for $Z_{e00} > 50 \Omega$, i.e., for inductive microstrip, $\varepsilon$ for
quartz = 3.8, and $\varepsilon_{er} (L)$ for inductor microstrip AB ($Z_{e00}
= 100 \Omega$) can be obtained from Eq. (3). $\varepsilon_{er}$ for capacitance
microstrip can be determined by first finding out $Z_{e00}$ corre-

FIG. 5. Measured $S_{11}$ parameters for the reso­
nator 1 (7-$\mu$m YIG film) with 1-mm un­
matched transducer are shown in alphabetic or­
ders denoted by small letters at frequencies: 3.0,
3.2, 3.4, 3.6, 3.8, 4.0, 4.2, 4.4, 4.6, 4.8, 5.0, 5.1,
5.2, 5.3, 5.4, 5.5, 5.55, 5.65, 5.75, 5.85, 5.95, and
6.0 GHz. Capital letters show measured $S_{11}$ at
above frequencies with matched transducer.

![Smith Chart](image)
\[ C = I_r / \beta_{rm} Z_{oc}, \]
\[ C_L = l_i / 2f Z_{oc} \lambda_{el}, \]
\[ l_i = (\lambda_{el}/2\pi)\sin^{-1}(\omega L_1/Z_{oc}). \]

\( Z_{oc} \) was used in the above equations as an unknown parameter, rather than the characteristic impedance of the 5-mm microstrip between B and A in Fig. 2. (At A and B there are microstrips of different characteristic impedances.) Next the width \( W \) of the inductor microstrip between B and C [Fig. 2(b)] was determined from
\[ Z_{oc} = \frac{119.9}{2(\varepsilon + 1)} \left[ \ln \left( \frac{4h_1}{w} + \left[ \frac{16(h_1)}{w} + 2 \right]^{0.5} \right) \right. 
- \left. 0.5 \left( \frac{\varepsilon - 1}{\varepsilon + 1} \right) \ln \frac{\pi}{2} + \frac{1}{\varepsilon} \ln \frac{4}{\pi} \right], \]

where \( h_1 = 0.25 \text{ mm} \) is the substrate thickness.

Final length \( IL \) and the width \( W \) of the inductor microstrip were calculated to be 1.1 mm and 131 \( \mu \text{m} \). The matched transducer was then fabricated through the usual photolithographic technique. The output transducer was a mirror image of the input transducer shown in Fig. 2. After matching the following improvements have been observed.

**RESULTS OF TRANSDUCER MATCHING**

1. It has been possible to reduce the insertion loss by 6 \( \text{dB} \) more, i.e., the insertion loss at resonance with most of the 1-mm resonators can be kept at 6–14 \( \text{dB} \) over 3 \( \text{GHz} \); the insertion loss as low as 6 \( \text{dB} \) at resonance has been obtained for some resonators (Fig. 4). Relative improvements at matching can be seen in Figs. 3(a), (b) and 4(a), (b). After matching we see that the \( S_{21} \) peak coincides with the \( S_{11} \) notch which results in reduced IL. The lowest IL achieved with a 1-mm matched transducer was 13 \( \text{dB} \) at 6 \( \text{GHz} \) with the resonator K2 (Table II).

2. The out-of-resonance rejection has been improved by 4 \( \text{dB} \), i.e., 10–14 \( \text{dB} \) within 3–6 \( \text{GHz} \). Before matching it was around 7–10 \( \text{dB} \). The maximum out-of-resonance rejection achieved with resonator K2 was more than 15 \( \text{dB} \).

3. The \( S_{11} \) parameters measured with a matched transducer have been found to be quite low (0.15) around 5–6 \( \text{GHz} \) when compared to those of the computer optimized values (see Smith chart A in Fig. 5). This is also reflected in the coincidence of reflection notch with resonance peak \( S_{21} \) (Figs. 3 and 4).

4. Tunability also improved significantly after matching. The resonators were tunable well beyond 6 \( \text{GHz} \) with minimum resonance rejection of 10 \( \text{dB} \) throughout the range (i.e., without the need of any tweaking).

With most of the resonators, matched transducers did not provide higher \( Q \) resonance.

**ACKNOWLEDGMENTS**

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